

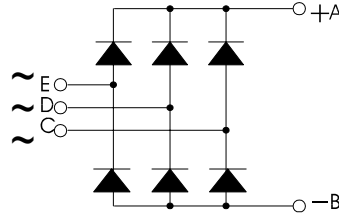
## Three Phase Rectifier Bridges

### PSD 51

$I_{dAVM} = 85 \text{ A}$   
 $V_{RRM} = 800-1800 \text{ V}$

Preliminary Data Sheet

$V_{RSM}$ V	$V_{RRM}$ V	Type
800	800	PSD 51/08
1200	1200	PSD 51/12
1400	1400	PSD 51/14
1600	1600	PSD 51/16
1800	1800	PSD 51/18



Symbol	Test Conditions	Maximum Ratings
$I_{dAVM}$	$T_C = 100^\circ\text{C}$ , module	85 A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	750 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	820 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	600 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	700 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	2800 $\text{A}^2 \text{ s}$
	$t = 8.3 \text{ ms}$ (60 Hz), sine	2820 $\text{A}^2 \text{ s}$
	$T_{VJ} = T_{VJM}$ $V_R = 0$ $t = 10 \text{ ms}$ (50 Hz), sine	2200 $\text{A}^2 \text{ s}$
	$t = 8.3 \text{ ms}$ (60 Hz), sine	2250 $\text{A}^2 \text{ s}$
$T_{VJ}$		-40 ... + 150 $^\circ\text{C}$
$T_{VJM}$		150 $^\circ\text{C}$
$T_{stg}$		-40 ... + 125 $^\circ\text{C}$
$V_{ISOL}$	50/60 HZ, RMS $t = 1 \text{ min}$	2500 V ~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V ~
$M_d$	Mounting torque (M5)	5 Nm
Weight	typ.	100 g

### Features

- Package with fast-on terminals
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 148688

### Applications

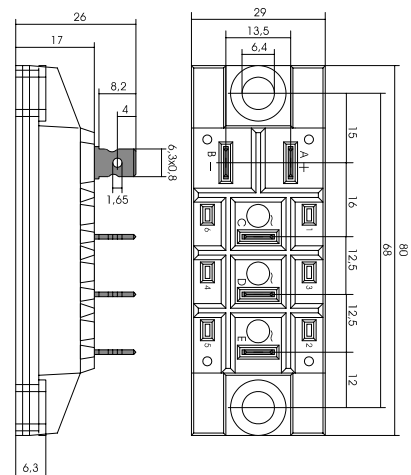
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability

### Package, style and outline

Dimensions in mm (1mm = 0.0394")



Symbol	Test Conditions	Characteristic Value
$I_R$	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 0.5 \text{ mA}$
	$V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$	$\leq 10 \text{ mA}$
$V_F$	$I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	$\leq 1.6 \text{ V}$
$V_{TO}$	For power-loss calculations only	0.8 V
$r_T$	$T_{VJ} = T_{VJM}$	6 $\text{m}\Omega$
$R_{thJC}$	per diode; DC current	1.3 K/W
	per module	0.22 K/W
$R_{thJK}$	per diode; DC current	1.6 K/W
	per module	0.27 K/W
$d_S$	Creeping distance on surface	16.1 mm
$d_A$	Creeping distance in air	7.5 mm
$a$	Max. allowable acceleration	50 $\text{m/s}^2$

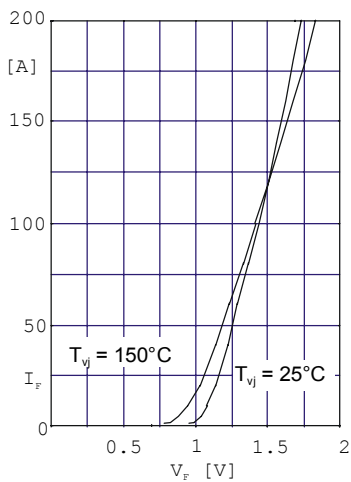


Fig. 1 Forward current versus voltage drop per diode

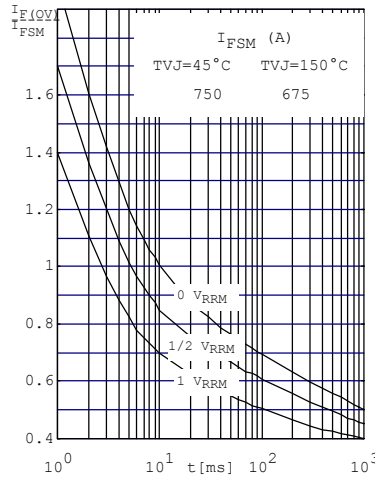


Fig. 2 Surge overload current per diode  $I_{FSM}$ : Crest value.  $t$ : duration

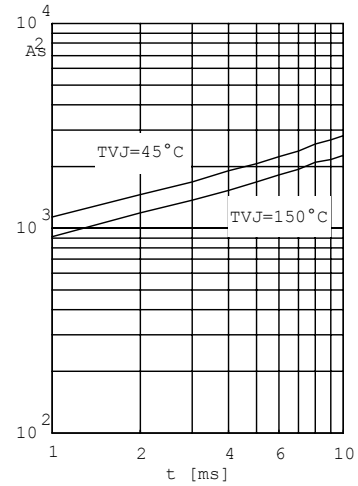


Fig. 3  $\int i^2 dt$  versus time (1-10ms) per diode (or thyristor)

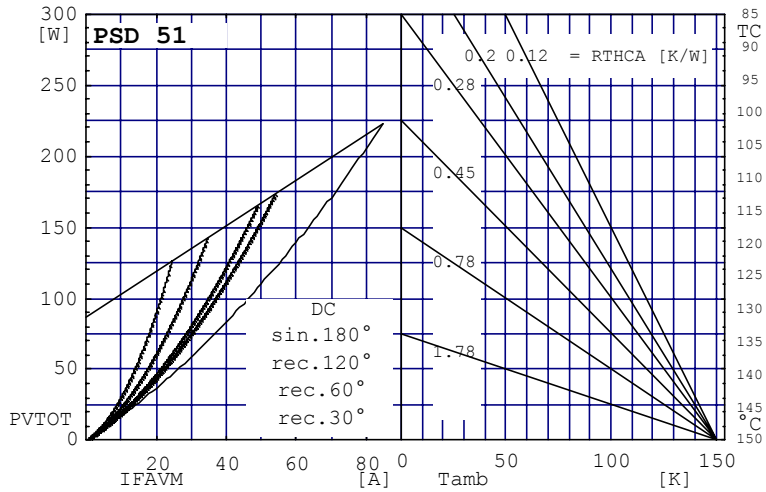


Fig. 4 Power dissipation versus direct output current and ambient temperature

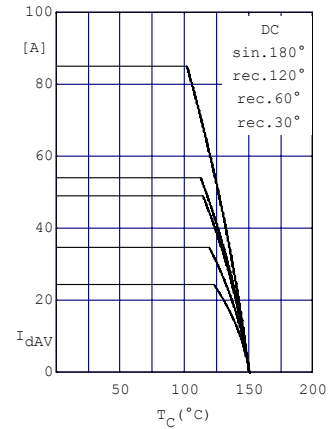


Fig.5 Maximum forward current at case temperature

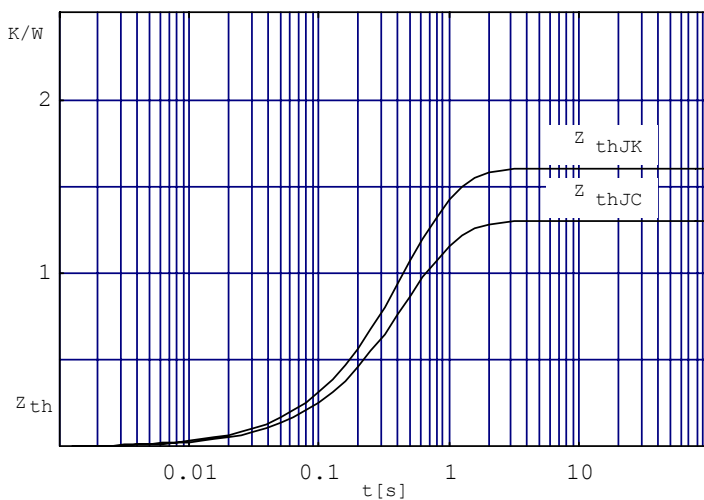


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Bridge Rectifiers](#) category:*

*Click to view products by [Powersem](#) manufacturer:*

Other Similar products are found below :

[G3SBA60-E351](#) [GBJ1504-BP](#) [GBU10B-BP](#) [GBU15J-BP](#) [GBU15K-BP](#) [GBU4A-BP](#) [GBU4D-BP](#) [GBU6B-E3/45](#) [GSIB680-E3/45](#) [DB101-BP](#) [DF10SA-E345](#) [RMB2S](#) [RCG](#) [APT30DF100HJ](#) [APT60DF20HJ](#) [B2S-E3/80](#) [BU1506-E351](#) [BU15085S-E345](#) [BU1508-E3/45](#) [BU1510-E3/45](#) [RS404GL-BP](#) [RS405GL-BP](#) [G3SBA20-E3/51](#) [G5SBA20-E3/51](#) [G5SBA60-E3/51](#) [GBJ1502-BP](#) [GBL02-E351](#) [GBL10-E3/45](#) [GBU10J-BP](#) [GBU4J-BP](#) [GBU4K-BP](#) [GBU8B-E3/45](#) [GBU8D-BP](#) [GBU8J-BP](#) [GSIB1520-E3/45](#) [MB1510](#) [MB352W](#) [MB6M-G](#) [B2M-E345](#) [B40C7000A](#) [B500C7000A](#) [MP5010W-BP](#) [MP501W-BP](#) [MP502-BP](#) [BR1005-BP](#) [BR101-BP](#) [BU1006-E345](#) [BU12065S-E3/45](#) [BU1508-E3/51](#) [BU2006-E3/45](#) [BU2008-E345](#)